

RoHS

COMPLIANT

HALOGEN

Available

Vishay Siliconix

N-Channel Reduced Q_g , Fast Switching MOSFET

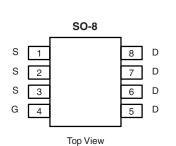
PRODUCT SUMMARY					
V _{DS} (V)	R_{DS(on)} (Ω)	I _D (A)			
12	0.0055 at V_{GS} = 4.5 V	17			
	0.008 at V _{GS} = 2.5 V	14			

FEATURES

- Halogen-free According to IEC 61249-2-21
 Available
- TrenchFET[®] Power MOSFETs
- PWM Optimized for High Efficiency
- Low Output Voltage
- 100 % R_g Tested

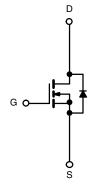
APPLICATIONS

- Synchronous Rectifier
- · Point-of-Load Synchronous Buck Converter



Ordering Information: Si4866DY-T1-E3 (Lead Pb)-free)

Si4866DY-T1-GE3 (Lead Pb)-free and Halogen-free)



N-Channel MOSFET

ABSOLUTE MAXIMUM RATINGS T	_A = 25 °C, unle	ss otherwise n	oted			
Parameter		Symbol	10 s	Steady State	Unit	
Drain-Source Voltage		V _{DS}	12		V	
Gate-Source Voltage		V _{GS}	± 8			
	T _A = 25 °C	1	17	11		
Continuous Drain Current (T _J = 150 °C) ^a	T _A = 70 °C	^I D	14	8	•	
Pulsed Drain Current		I _{DM}	± 50		A	
Continuous Source Current (Diode Conduction) ^a		۱ _S	2.7	1.40		
	T _A = 25 °C	PD	3.0	1.6	W	
Maximum Power Dissipation ^a	T _A = 70 °C		2.0	1.0	vv	
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 to 150		°C	

THERMAL RESISTANCE RATINGS					
Parameter		Symbol	Typical	Maximum	Unit
Maximum Junction-to-Ambient (MOSFET) ^a	t ≤ 10 s	R _{thJA}	34	41	
	Steady State	' 'thJA	67	80	°C/W
Maximum Junction-to-Foot (Drain)	Steady State	R _{thJF}	15	19	

Notes:

a. Surface Mounted on 1" x 1" FR4 board.

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otherwise noted				
Test Conditions	Min.	Тур.	Max.	Unit
	-			
$_{\rm OS} = V_{\rm GS}, \ {\rm I_D} = 250 \ {\rm \mu A}$	0.6			V
_{DS} = 0 V, V _{GS} = ± 8 V			± 100	nA

Static						
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}$, $I_D = 250 \ \mu A$	0.6			V
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 V, V_{GS} = \pm 8 V$			± 100	nA
Zero Gate Voltage Drain Current	I _{DSS}	$V_{DS} = 9.6 V, V_{GS} = 0 V$			1	μΑ
		$V_{DS} = 9.6 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 70 ^{\circ}\text{C}$			5	
On-State Drain Current ^a	I _{D(on)}	$V_{DS} \ge 5 V$, $V_{GS} = 4.5 V$	40			А
Drain-Source On-State Resistance ^a	B	V _{GS} = 4.5 V, I _D = 17		0.0045	0.0055	Ω
	R _{DS(on)}	$V_{GS} = 2.5 \text{ V}, \text{ I}_{D} = 14$		0.0065	0.008	
Forward Transconductance ^a	9 _{fs}	$V_{DS} = 6 \text{ V}, \text{ I}_{D} = 17$		80		S
Diode Forward Voltage ^a	V_{SD}	$I_{\rm S}$ = 2.7 A, $V_{\rm GS}$ = 0 V		0.70	1.1	V
Dynamic ^b				•		
Total Gate Charge	Qg			21	30	nC
Gate-Source Charge	Q _{gs}	V_{DS} = 6 V, V_{GS} = 4.5 V, I_D = 17 A		4.6		
Gate-Drain Charge	Q _{gd}			3.5		
Gate Resistance	R _G		1.5	2.3	3.9	Ω
Turn-On Delay Time	t _{d(on)}			28	42	
Rise Time	t _r	$V_{DD} = 6 \text{ V}, \text{ R}_{L} = 6 \Omega$		32	48	ns
Turn-Off Delay Time	t _{d(off)}	$\text{I}_\text{D}\cong \text{1}$ A, V_GEN = 4.5 V, R_G = 6 Ω		82	123	
Fall Time	t _f			35	53	
Source-Drain Reverse Recovery Time	t _{rr}	I _F = 2.7 A, dI/dt = 100 A/μs		60	90	

Notes:

a. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %.

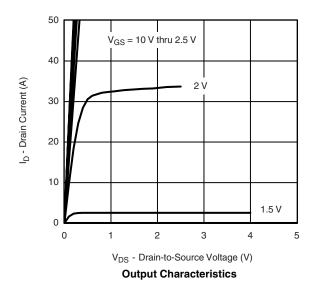
b. Guaranteed by design, not subject to production testing.

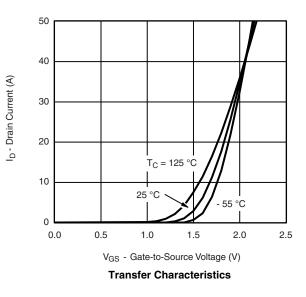
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

MOSFET SPECIFICATIONS T_J = 25 °C, unless otherwise

Symbol





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Si4866DY

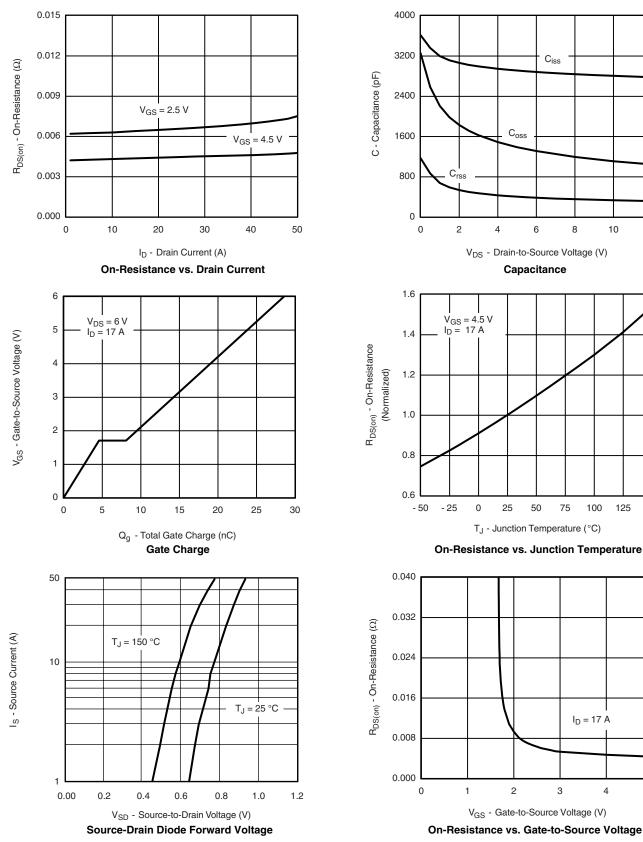
12

150

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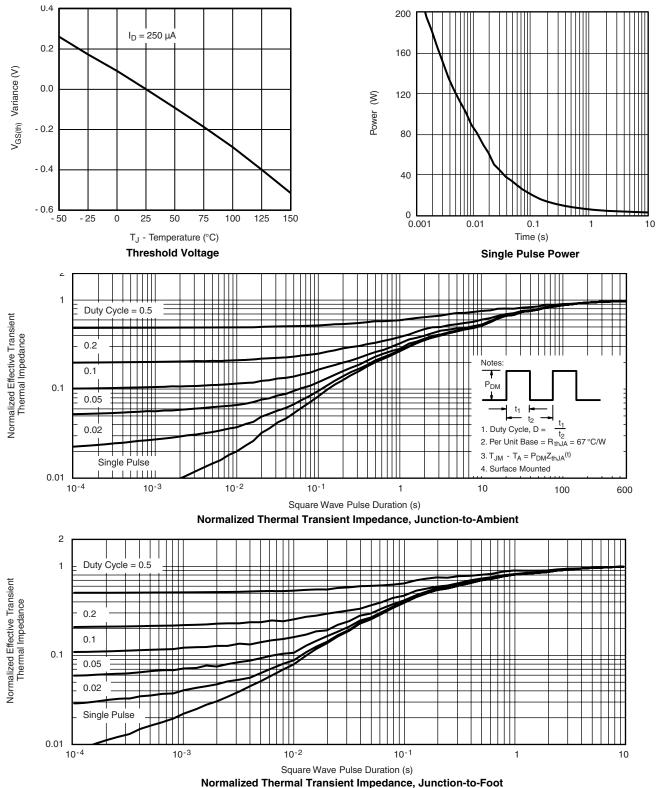


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Si4866DY

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TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg?71699.

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